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[TSOP7000](#)

**EN**

This Datasheet is presented by  
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**DE**

Dieses Datenblatt wird vom  
Hersteller bereitgestellt

**FR**

Cette fiche technique est  
présentée par le fabricant

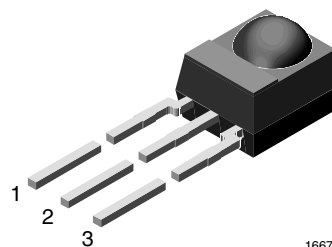
## IR Receiver for High Data Rate PCM at 455 kHz

### Description

The TSOP7000 is a miniaturized receiver for infrared remote control and IR data transmission. PIN diode and preamplifier are assembled on lead frame, the epoxy package is designed as IR filter.

The demodulated output signal can directly be decoded by a microprocessor. The main benefit is the operation with high data rates and long distances.

This component has not been qualified according to automotive specifications.



### Features

- Photo detector and preamplifier in one package
- Internal Bandfilter for PCM frequency
- Internal shielding against electrical field disturbance
- TTL and CMOS compatibility
- Output active low
- Small size package
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



### Special Features

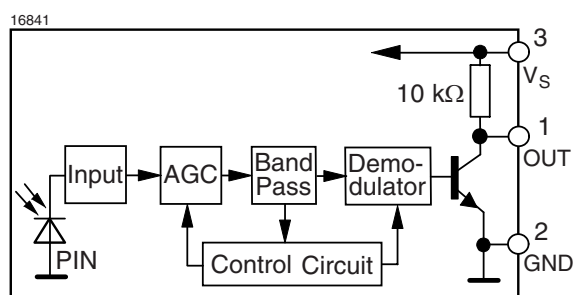
- Data rate 20 kbit/s
- Supply voltage 2.7 - 5.5 V
- Short settling time after power on
- High envelope duty cycle can be received
- Enhanced immunity against disturbance from energy saving lamps

### Mechanical Data

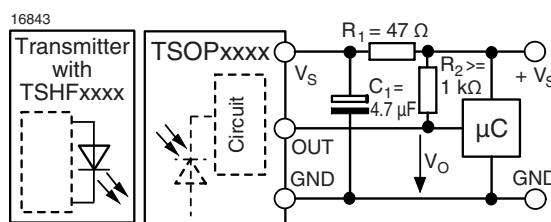
#### Pinning:

1 = OUT, 2 = GND, 3 =  $V_S$

### Block Diagram



### Application Circuit



$R_1 + C_1$  recommended to suppress power supply disturbances.

$R_2$  optional for improved pulse forming.

## Absolute Maximum Ratings

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Supply Voltage	Pin 3	$V_S$	-0.3 to + 6.0	V
Voltage at output to supply	Pin 1	$V_S - V_O$	-0.3 to ( $V_S + 0.3$ )	V
Supply Current	Pin 3	$I_S$	5	mA
Output Voltage	Pin 1	$V_O$	-0.3 to + 6.0	V
Output Current	Pin 1	$I_O$	15	mA
Junction Temperature		$T_j$	100	$^{\circ}\text{C}$
Storage Temperature Range		$T_{stg}$	- 25 to + 85	$^{\circ}\text{C}$
Operating Temperature Range		$T_{amb}$	- 25 to + 85	$^{\circ}\text{C}$
Soldering Temperature	$t \leq 10\text{ s}$ , 1 mm from case	$T_{sd}$	260	$^{\circ}\text{C}$
Power Consumption		$P_{tot}$	30	mW

## Electrical and Optical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Supply Current (Pin 3)	Dark ambient	$I_{SD}$		2.0	2.7	mA
	$E_v = 40\text{ klx}$ , sunlight	$I_{SH}$		2.3		mA
Supply Voltage (Pin 3)		$V_S$	2.7	5	5.5	V
Transmission Distance	$\lambda_p = 870\text{ nm}$ , IR Diode TSHF5400, $I_F = 300\text{ mA}$	$d_{max}$		20		m
	$\lambda_p = 950\text{ nm}$ , IR Diode TSAL6400, $I_F = 300\text{ mA}$	$d_{max}$		12		m
Threshold Irradiance	$\lambda_p = 870\text{ nm}$ , optical test signal of fig. 1	$E_{e\ min}$		0.8	1.5	$\text{mW/m}^2$
Maximum Irradiance	Optical test signal of fig. 1	$E_{e\ max}$	30			$\text{W/m}^2$
Output Voltage Low (Pin 1)	1 $\text{k}\Omega$ external pull up resistor	$V_{QL}$			100	mV
Output Voltage High (Pin 1)	No external pull-up resistor	$V_{QH}$	$V_S - 0.25$			V
Bandpass filter quality		$Q$		10		
Out-Pulse width tolerance	Optical test signal of fig.1, $1.5\text{ mW/m}^2 \leq E_e \leq 30\text{ W/m}^2$	$\Delta t_{po}$	- 15	+ 5	+ 15	$\mu\text{s}$
Delay time of output pulse	Optical test signal of fig. 1, $E_e > 1.5\text{ mW/m}^2$	$t_{don}$	15		36	$\mu\text{s}$
Receiver start up time	Valid data after power on	$t_V$		50		$\mu\text{s}$
Falling time	Leading edge of output pulse	$t_f$		0.4		$\mu\text{s}$
Rise time	No external pull up resistor	$t_r$		12		$\mu\text{s}$
	1 $\text{k}\Omega$ external pull up resistor	$t_r$		1.2		$\mu\text{s}$
Directivity	Angle of half transmission distance	$\Phi_{1/2}$		$\pm 45$		deg

### Typical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

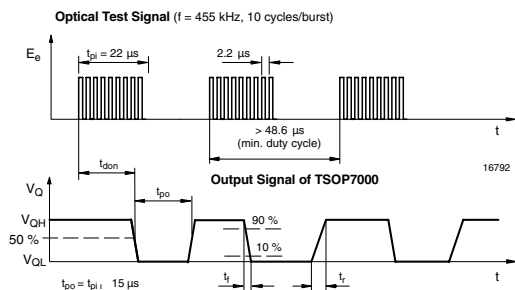


Figure 1. Output Function

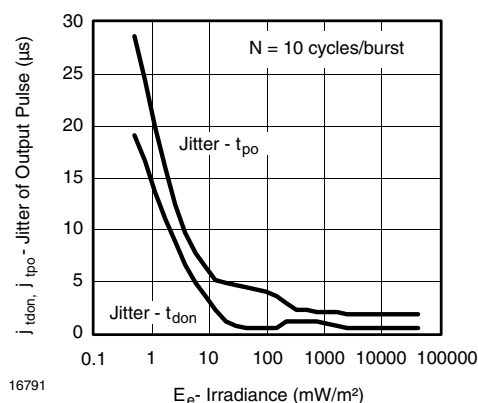


Figure 4. Jitter of Output Pulse

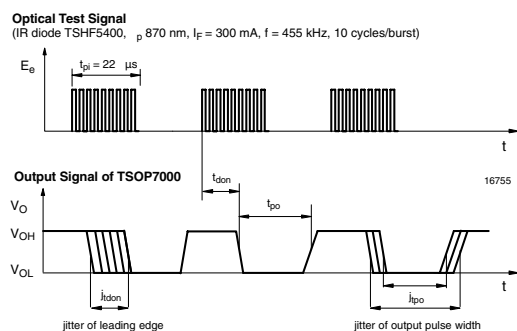


Figure 2. Output Function (mit Jitter)

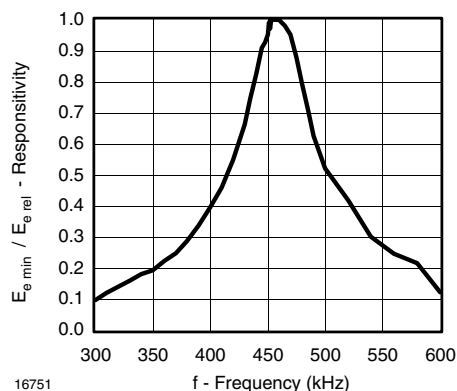


Figure 5. Frequency Dependence of Responsivity

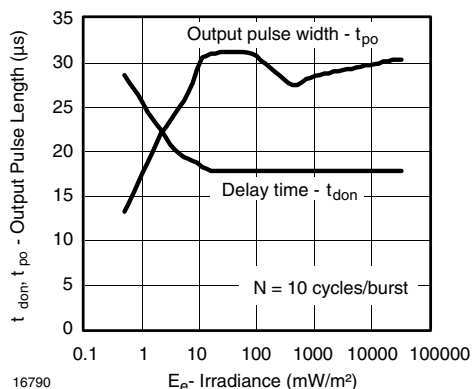


Figure 3. Output Pulse Diagram ( $t_{don}$ ,  $t_{po}$ )

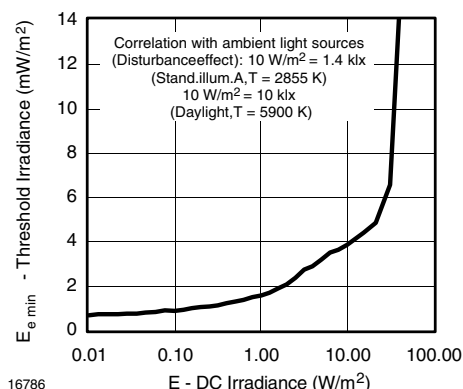


Figure 6. Sensitivity in Bright Ambient

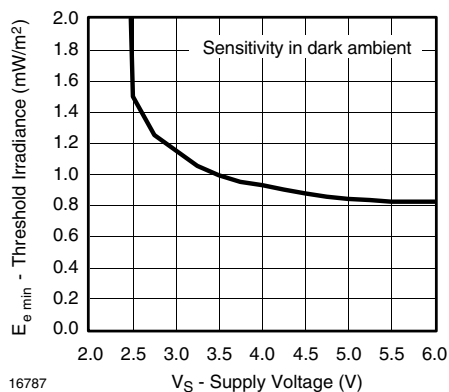


Figure 7. Sensitivity vs. Supply Voltage

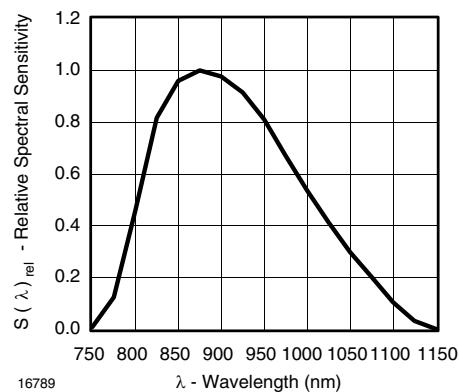


Figure 10. Relative Spectral Sensitivity vs. Wavelength

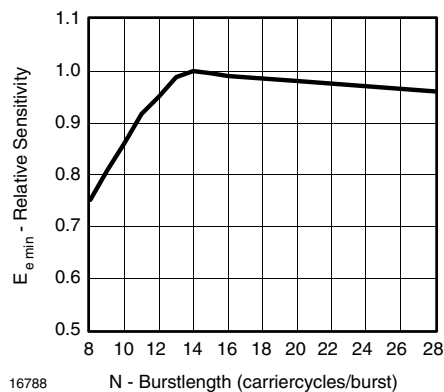


Figure 8. Rel. Sensitivity vs. Burstlength

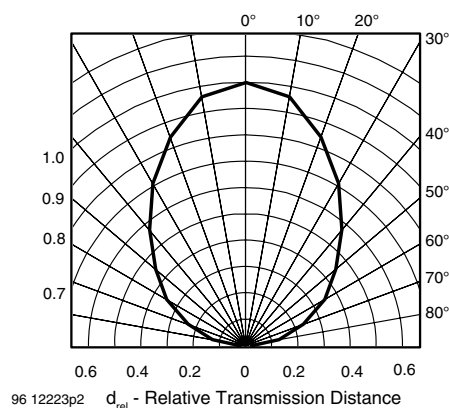


Figure 11. Directivity

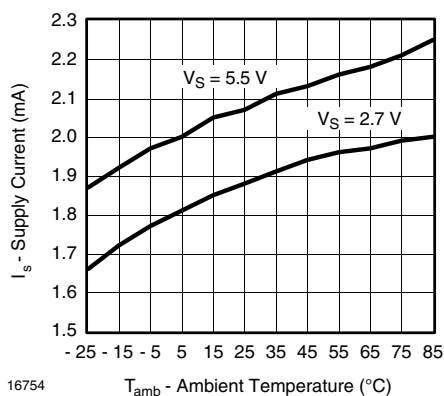


Figure 9. Supply Current vs. Ambient Temperature

## Recommendation for Suitable Data Formats

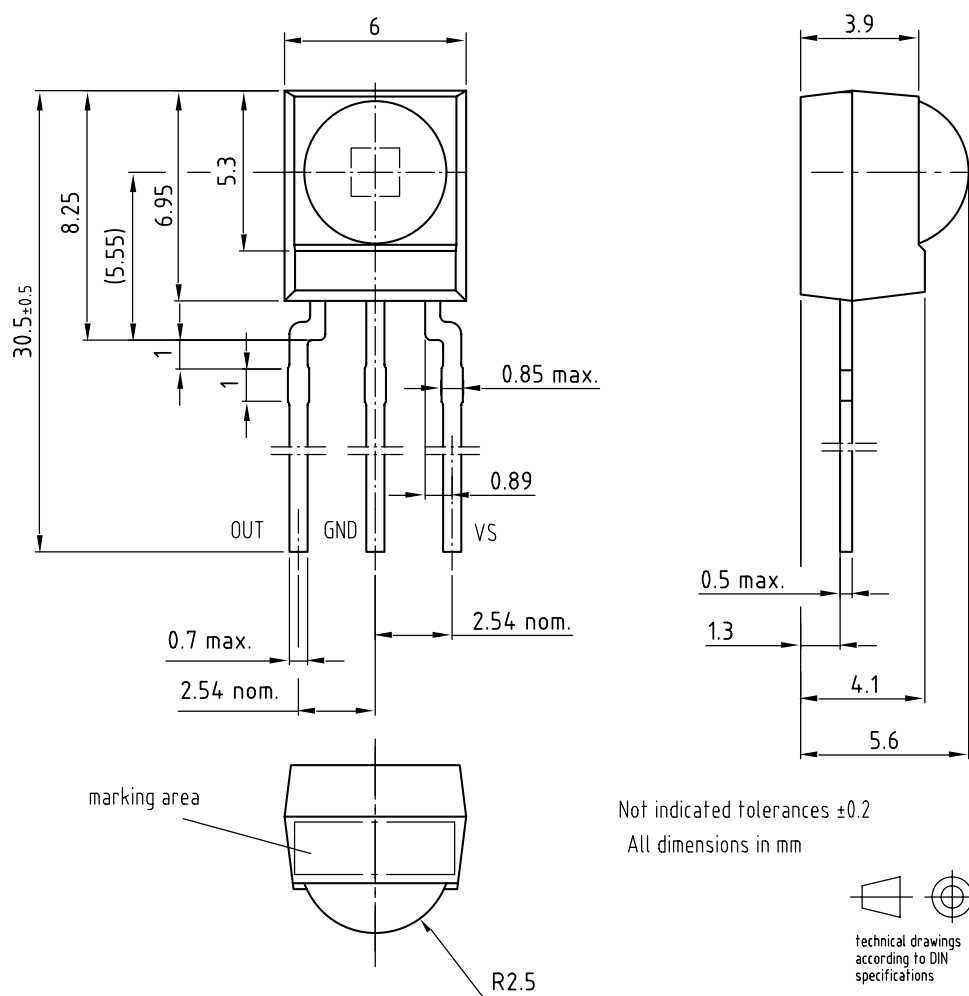
The circuit of the TSOP7000 is designed so that disturbance signals are identified and unwanted output pulses due to noise or disturbances are avoided. A bandpass filter, an automatic gain control and an integrator stage is used to suppress such disturbances. The distinguishing marks between data signal and disturbance are carrier frequency, burst length and the envelope duty cycle.

The data signal should fulfill the following conditions:

- The carrier frequency should be close to 455 kHz.

- The burstlength should be at least 22  $\mu\text{s}$  (10 cycles of the carrier signal) and shorter than 500  $\mu\text{s}$ .
- The separation time between two consecutive bursts should be at least 26  $\mu\text{s}$ .
- If the data bursts are longer than 500  $\mu\text{s}$  then the envelope duty cycle is limited to 25 %
- The duty cycle of the carrier signal (455 kHz) may be between 50 % (1.1  $\mu\text{s}$  pulses) and 10 % (0.2  $\mu\text{s}$  pulses). The lower duty cycle may help to save battery power.

## Package Dimensions in millimeters



Drawing-No.: 6.550-5169.11-4

Issue: 10; 08.06.04

16003

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2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

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3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

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